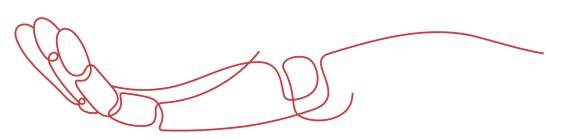




# **PRODUCT DATA SHEET**



To learn more about JGSEMI, please visit our website at







Datasheet

es Samples

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO\_questions@jgsemi.com.



ULTRA LOW CAPACITANCE BIDIRECTIONAL TVS DIODE

#### **Features**

Ultra low leakage: nA level

• Operating voltage: 5V

Low clamping voltage

Complies with following standards:

- IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-4 (EFT) 40A (5/50ns)

- IEC61000-4-5 (Lightning) 4.5A (8/20 μs)

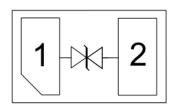
RoHS Compliant



**DFN1006** 

### **Applications**

- Smart phones
- Display Ports
- MDDI Ports
- USB Ports
- Digital Video Interface (DVI)
- PCI Express and Serial SATA Ports



#### **Mechanical Characteristics**

Package: DFN1006

Lead Finish: Lead Free

UL Flammability Classification Rating 94V-0

Quantity Per Reel:10,000pcs

Reel Size:7 inch

### Absolute Maximum Ratings(Tamb=25°C unless otherwise specified)

| Parameter                       | Symbol | Value       | Unit          |  |
|---------------------------------|--------|-------------|---------------|--|
| Peak Pulse Power (8/20µs)       | Ррр    | 110         | W             |  |
| ESD per IEC 61000-4-2 (Air)     | - Vesd | ± 30        | Kv            |  |
| ESD per IEC 61000-4-2 (Contact) | VESD   | ± 30        | ΓV            |  |
| Operating Temperature Range     | TJ     | -55 to +150 | ${\mathbb C}$ |  |
| Storage Temperature Range       | Тѕтл   | -55 to +150 | $^{\circ}$    |  |

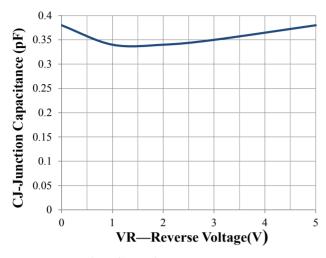


# Electrical Characteristics (TA=25°C unless otherwise specified)

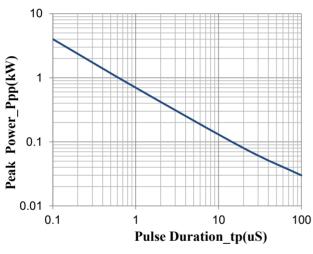
| Parameter               | Symbol           | Test Condition                  | Min | Тур  | Max | Unit |
|-------------------------|------------------|---------------------------------|-----|------|-----|------|
| Reverse Working Voltage | V <sub>RWM</sub> |                                 |     |      | 5   | V    |
| Breakdown Voltage       | $V_{BR}$         | Iτ = 1mA                        | 6   |      |     | V    |
| Reverse Leakage Current | I <sub>R</sub>   | V <sub>RWM</sub> = 5V           |     |      | 0.5 | μA   |
| Clamping Voltage        | V <sub>C</sub>   | IPP = 1A (8 x 20 µs pulse)      |     |      | 12  | V    |
| Clamping Voltage        | V <sub>C</sub>   | IPP = 4.5A (8 x 20 \mu s pulse) |     |      | 23  | V    |
| Junction Capacitance    | Сл               | V <sub>R</sub> = 0V, f = 1MHz   |     | 0.22 |     | pF   |



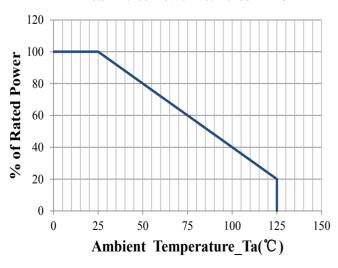
#### Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise Specified)



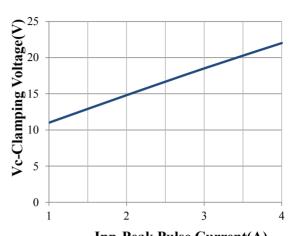
Junction Capacitance vs. Reverse Voltage



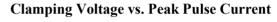
Peak Pulse Power vs. Pulse Time

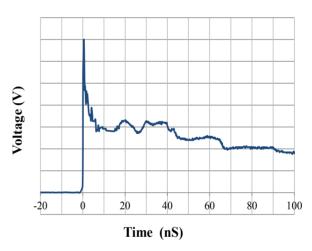


**Power Derating Curve** 

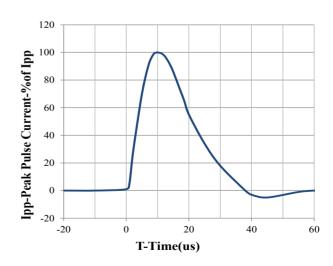


Ipp-Peak Pulse Current(A)





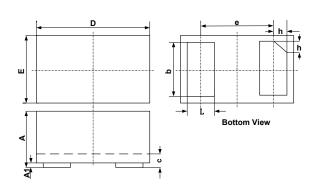
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

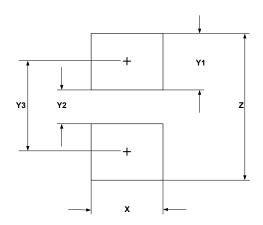


## **DFN1006 Package Outline Drawing**



|       | DIMENSIONS  |      |      |        |          |          |
|-------|-------------|------|------|--------|----------|----------|
| 21/12 | MILLIMETERS |      |      | INCHES |          |          |
| SYM   | MIN         | NOM  | MAX  | MIN    | NOM      | MAX      |
| Α     | 0.45        | 0.50 | 0.55 | 0.018  | 0.020    | 0.022    |
| A1    | 0.00        | 0.02 | 0.05 | 0.000  | 0.001    | 0.002    |
| b     | 0.45        | 0.50 | 0.55 | 0.018  | 0.020    | 0.022    |
| С     | 0.12        | 0.15 | 0.18 | 0.005  | 0.006    | 0.007    |
| D     | 0.95        | 1.00 | 1.05 | 0.037  | 0.039    | 0.041    |
| е     | 0.65 BSC    |      |      | C      | 0.026 BS | <u> </u> |
| Е     | 0.55        | 0.60 | 0.65 | 0.022  | 0.024    | 0.026    |
| L     | 0.20        | 0.25 | 0.30 | 0.008  | 0.010    | 0.012    |
| h     | 0.07        | 0.12 | 0.17 | 0.003  | 0.005    | 0.007    |

## **Suggested Land Pattern**



| SYM   | DIMENSIONS  |        |  |
|-------|-------------|--------|--|
| STIVI | MILLIMETERS | INCHES |  |
| Х     | 0.60        | 0.024  |  |
| Y1    | 0.50        | 0.020  |  |
| Y2    | 0.30        | 0.012  |  |
| Y3    | 0.80        | 0.032  |  |
| Z     | 1.30        | 0.052  |  |



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